

MBRH20045 thru MBRH200100R

Silicon Power Schottky Diode

 $V_{RRM} = 45 \text{ V} - 100 \text{ V}$

 $I_{F(AV)} = 200 A$

Features

- High Surge Capability
- \bullet Types from 45 V to 100 V V_{RRM}
- Not ESD Sensitive













Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

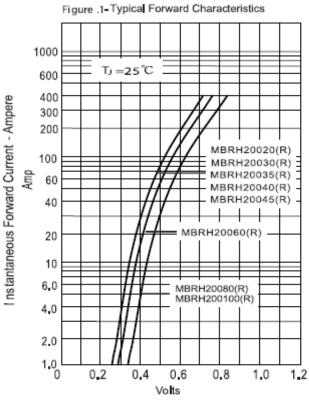
Parameter	Symbol	Conditions	MBRH20045(R)	MBRH20060(R)	MBRH20080(R)	MBRH200100(R)	Unit
Repetitive peak reverse voltage	V_{RRM}		45	60	80	100	V
RMS reverse voltage	V _{RMS}		32	42	57	70	V
DC blocking voltage	V _{DC}		45	60	80	100	V
Operating temperature	T _j		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

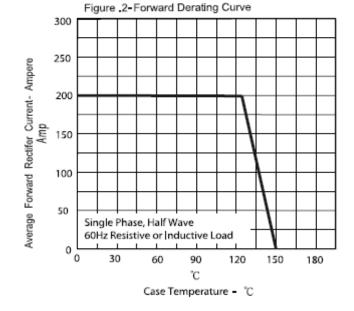
Electrical characteristics, at Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	MBRH20045(R)	MBRH20060(R)	MBRH20080(R)	MBRH200100(R)	Unit	
Average forward current (per pkg)	I _F	T _C ≤ 136 °C	200	200	200	200	Α	
Peak forward surge current	I_{FSM}	$T_C = 25 ^{\circ}C, t_p = 8.3 \text{ms}$	3000	3000	3000	3000	Α	
Maximum instantaneous forward voltage	V_{F}	I _{FM} = 200 A, T _j = 25 °C	0.70	0.75	0.84	0.84	V	
Maximum instantaneous		T _j = 25 °C	1	1	1	1		
reverse current at rated DC	C I _R	$T_j = 100 ^{\circ}\text{C}$	10	10	10	10	mA	
blocking voltage		$T_j = 150 ^{\circ}C$	50	50	50	50		
Thermal characteristics								
Thermal resistance, junction - case	R_{thJC}		0.35	0.35	0.35	0.35	°C/W	

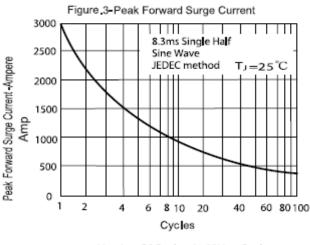


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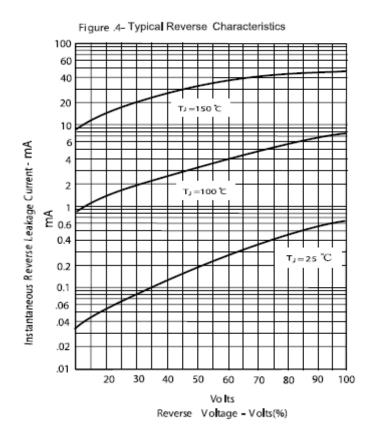








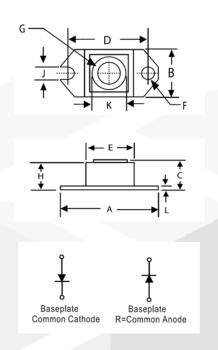
Number Of Cycles At 60Hz - Cycles



MBRH20045 thru MBRH200100R

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIMENS IONS							
DIM	INCH	IES	М	NOTE			
	MIN	MAX	MIN	MAX			
Α	1.515	1.560	38.48	39.62			
В	.725	.775	18.42	19.69			
С	.595	.625	15.11	15.88			
D	1.182	1.192	30.02	30.28			
Е	.736	.744	18.70	18.90			
F	.152	.160	3.86	4.061	Ø		
G	G 1/4- 20 UNC						
Н	.540	.580	13.72	14.73			
J	.156	.160	3.96	4.06			
К	.480	.492	12.20	12.50	Ø		
L	.120	.130	3.05	3.30			

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M252511FV DD2	260N12K-A	DD380N16A	DD89N1600K-	$\underline{\mathbf{A}}$ $\underline{\mathbf{APT2X21D0}}$	C60J <u>APT58M</u>	80J B522F-2-Y	YEC MSTC90-1	6 25.163.0653.1
<u>25.163.2453.0</u> <u>25.</u>	163.4253.0	25.190.2053.0	25.194.3453.0	25.320.4853.1	25.320.5253.1	25.326.3253.1	25.326.3553.1	25.330.1653.1
<u>25.330.4753.1</u> <u>25.</u>	330.5253.1	25.334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>	T485F T485H
T512F-YEB T513	<u>F T514F T</u>	<u>T612FSE</u>	25.161.3453.0	25.179.2253.0	25.194.3253.0	25.325.1253.1	25.326.4253.1	25.330.0953.1
<u>25.332.4353.1</u> <u>25.</u>	350.1653.0	25.350.2453.0	25.352.1453.0	25.352.1653.0	25.352.2453.0	25.352.5453.1	25.522.3353.0	25.602.4053.0
25.640.5053.0								